

FEATURES

- LOW COST
- WIDE BANDWIDTH - 1.1 Mhz
- HIGH OUTPUT CURRENT - 2.5A (Combined)
- WIDE COMMON MODE RANGE Includes negative supply
- WIDE SUPPLY VOLTAGE RANGE Single supply: 5V to 40V
Split supplies: $\pm 2.5V$ to $\pm 20V$
- LOW QUIESCIENT CURRENT
- VERY LOW DISTORTION

APPLICATIONS

- HALF AND FULL BRIDGE MOTOR DRIVERS
- AUDIO POWER AMPLIFIER
- IDEAL FOR SINGLE SUPPLY SYSTEMS
5V Peripherals, 12V Automotive, 28V Avionic

PACKAGING OPTIONS

- 7 TO-220 Plastic Package (PA75CD)
- 7 TO-220 with Staggered Lead Form (PA75CX)
- 7 DDPAK Surface Mount Package (PA75CC)

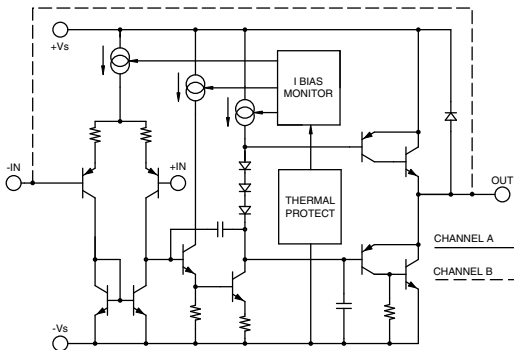
DESCRIPTION

The amplifier design consists of dual power op amp on a single monolithic die. Side B of the dual monolithic is configured as a unity gain buffer to increase the current capability of the master side A. The use of two PA75 amplifiers provides a cost-effective solution to applications where multiple amplifiers are required or a bridge configuration is needed. Very low harmonic distortion of .02% THD and low I_Q makes the PA75 a good solution for power audio applications.

The PA75 is available in three standard package designs. The surface mount version of the PA75, the PA75CC, is an industry standard non-hermetic plastic 7-pin DDPAK. The through hole version of the PA75, the PA75CD and PA75CX, are industry standard non-hermetic plastic 7-pin TO-220 packages. The PA75CX is staggered lead formed and offers standard 100 mil spacing. This allows for easier PC board layout. (Please refer to the CX lead form package drawing for dimension of the PA75CX).

The monolithic amplifier is directly attached to the metal tabs of the PA75CC, PA75CD, and PA75CX. The metal tabs of the packages are directly tied to $-V_s$.

EQUIVALENT SCHEMATIC ONE CHANNEL



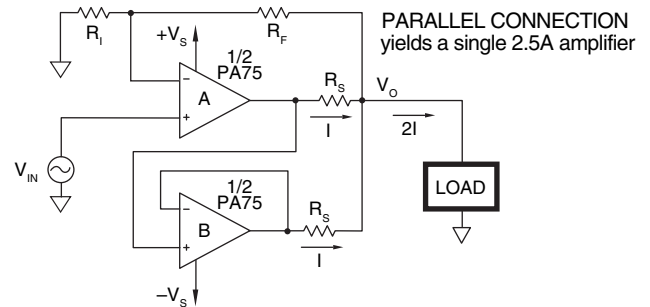
7 PIN DDPAK
PACKAGE STYLE CC

7 PIN TO220
STAGGERED LEADS
PACKAGE STYLE CX

7 PIN TO220
PACKAGE STYLE CD

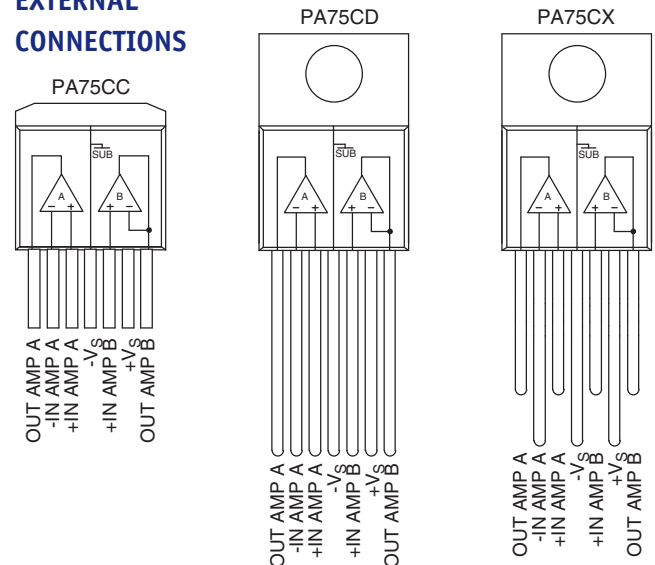
TYPICAL APPLICATION

Ref: APPLICATION NOTES 8, 20, 26



Combining the power op amp (master channel A) and the unity gain buffer (slave channel B) in a parallel connection yields a single 2.5A amplifier. R_I and R_F can set up channel A for the required gain for the overall circuit. Small values of R_S (sense resistors) are used on the outputs to improve current sharing characteristics. The master amplifier can be configured in inverting or non-inverting gain configurations.

EXTERNAL CONNECTIONS



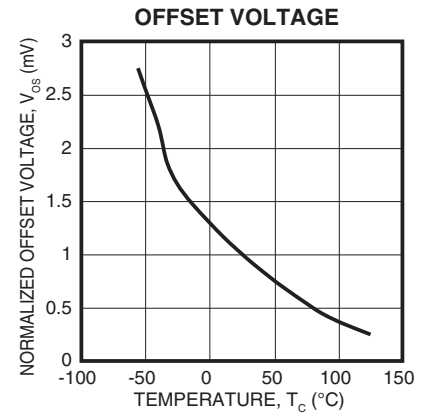
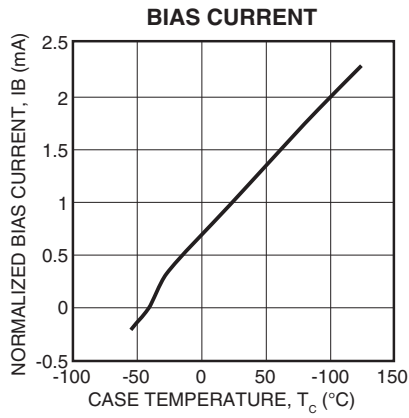
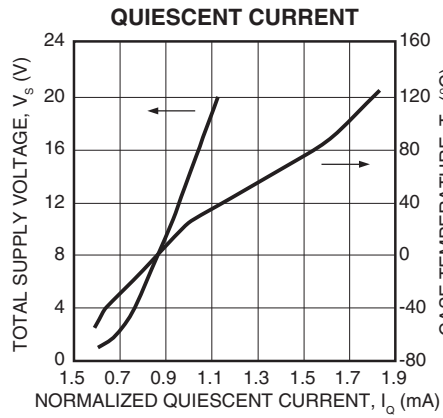
ABSOLUTE MAXIMUM RATINGS

SUPPLY VOLTAGE, total	5V to 40V
OUTPUT CURRENT	SOA
POWER DISSIPATION, internal, (per amplifier)	19.5W
POWER DISSIPATION, internal (both amplifiers)	28.6W
INPUT VOLTAGE, differential	$\pm V_S$
INPUT VOLTAGE, common mode	$+V_S, -V_S-0.5V$
JUNCTION TEMPERATURE, max ¹	150°C
TEMPERATURE, pin solder—10 sec max	220°C
TEMPERATURE RANGE, storage	-55°C to 150°C
OPERATING TEMPERATURE RANGE, case	-40°C to 125°C

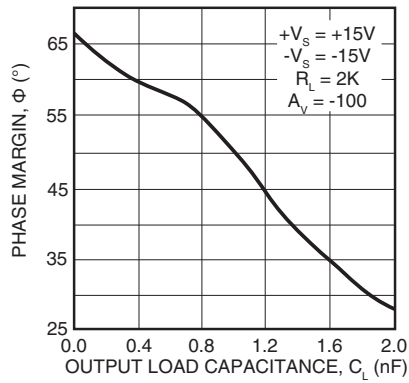
SPECIFICATIONS

PARAMETER	TEST CONDITIONS ²	MIN	TYP	MAX	UNITS
INPUT					
OFFSET VOLTAGE, initial			1	15	mV
OFFSET VOLTAGE, vs. temperature	Full temperature range		20		$\mu V/^\circ C$
BIAS CURRENT, initial			100	500	nA
COMMON MODE RANGE	Full temperature range	$-V_S$		$+V_S-1.3$	V
COMMON MODE REJECTION, DC	Full temperature range	60	90		dB
POWER SUPPLY REJECTION	Full temperature range	60	90		dB
CHANNEL SEPARATION	$I_{OUT} = 500mA, f = 1kHz$	50	68		dB
INPUT NOISE VOLTAGE	$R_S = 100\Omega, f = 1$ to 100kHz		22		nV/\sqrt{Hz}
GAIN					
OPEN LOOP GAIN	Full temperature range	89	100		dB
GAIN BANDWIDTH PRODUCT	$A_V = 40dB$	0.9	1.4		MHz
PHASE MARGIN	Full temperature range, $R_L = 2K\Omega, C_L = 100pF$		65		°
POWER BANDWIDTH	$V_{O(P-P)} = 28V$		13.6		kHz
OUTPUT					
CURRENT, peak				1.5	A
SLEW RATE		1	1.4		V/ μs
VOLTAGE SWING	Full Temperature Range, $I_O = 100mA$	$ V_S - 1.1$	$ V_S - .8$		V
VOLTAGE SWING	Full Temperature Range, $I_O = 1A$	$ V_S - 1.8$	$ V_S - 1.4$		V
HARMONIC DISTORTION	$A_V = 1, R_2 = 50\Omega, V_O = .5V_{RMS}, f = 1kHz$.02		%
POWER SUPPLY					
VOLTAGE, V_{SS}^3		5	30	40	V
CURRENT, quiescent, total			8	10	mA
THERMAL					
RESISTANCE,DC junction to case (single)			5.84	6.42	$^\circ C/W$
RESISTANCE,AC junction to case (single)			4.38	4.81	$^\circ C/W$
RESISTANCE,DC junction to case (both)			3.97	4.36	$^\circ C/W$
RESISTANCE,AC junction to case (both)			2.98	3.27	$^\circ C/W$
RESISTANCE,junction to air (CD,CX)			60		$^\circ C/W$
RESISTANCE,junction to air (CC) ⁴			27		$^\circ C/W$
TEMPERATURE RANGE,case	Meets full range specifications	-25		85	$^\circ C$

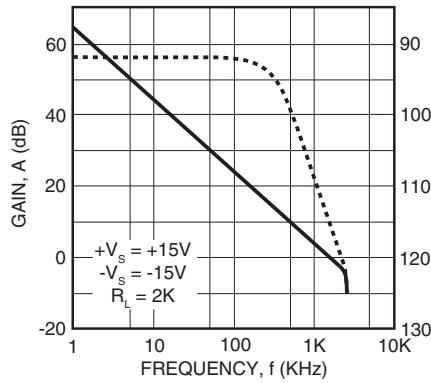
- NOTES: 1. Long term operation at the maximum junction temperature will result in reduced product life. Derate internal power dissipation to achieve high MTTF.
 2. Unless otherwise noted, the following conditions apply: $\pm V_S = \pm 15V, T_C = 25^\circ C$.
 3. $+V_S$ and $-V_S$ denote the positive and negative supply rail respectively. V_{SS} denotes the total rail-to-rail supply voltage.
 4. Heat tab attached to 3/32" FR-4 board with 2oz. copper. Topside copper area (heat tab directly attached) = 1000 sq. mm, back-side copper area = 2500 sq. mm, board area = 2500 sq. mm.



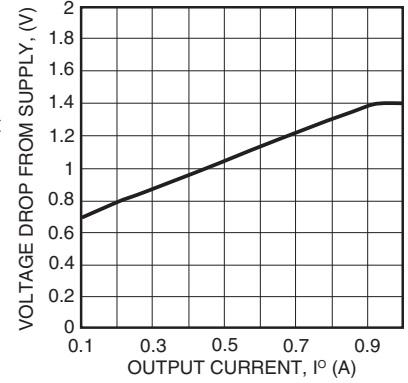
PHASE MARGIN vs. OUTPUT LOAD CAPACITANCE



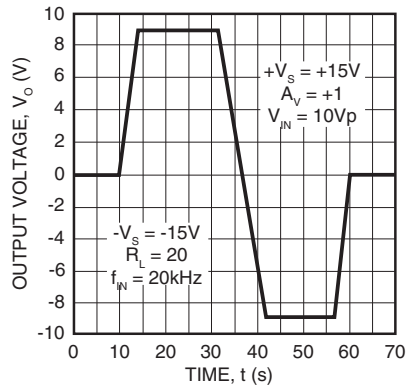
VOLTAGE GAIN & PHASE vs. FREQUENCY



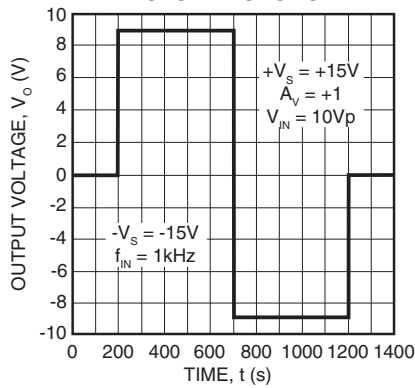
OUTPUT VOLTAGE SWING



PULSE RESPONSE



PULSE RESPONSE

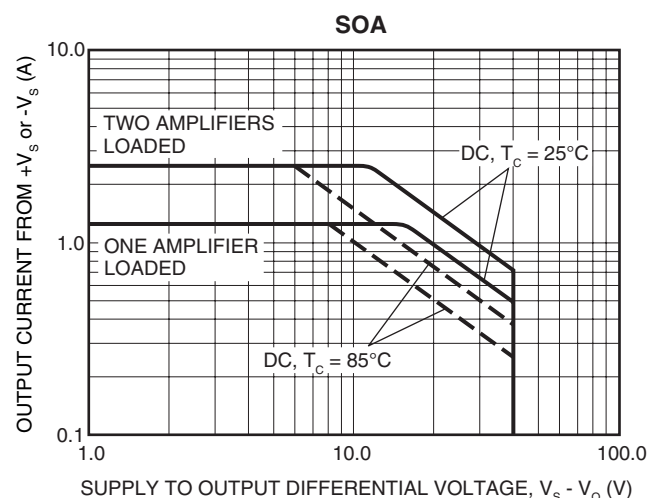


GENERAL

Please read Application Note 1 "General Operating Considerations" which covers stability, supplies, heatsinking, mounting, SOA interpretation, and specification interpretation. Visit www.apexmicrotech.com for design tools that help automate tasks such as calculations for stability, internal power dissipation, heatsink selection; Apex's complete Application Notes library; Technical Seminar Workbook; and Evaluation Kits.

STABILITY CONSIDERATIONS

All monolithic power op amps use output stage topologies that present special stability problems. This is primarily due to non-complementary (both devices are NPN) output stages with a mismatch in gain and phase response for different polarities of output current. It is difficult for the op amp manufacturer to optimize compensation for all operating conditions.



SAFE OPERATING AREA (SOA)

The SOA curves combine the effect of all limits for this power op amp. For a given application, the direction and magnitude of the output current should be calculated or measured and checked against the SOA curves. This is simple for resistive loads but more complex for reactive and EMF generating loads.

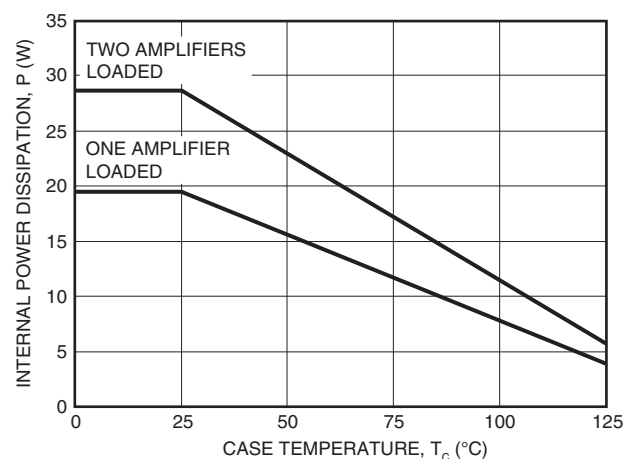
THERMAL CONSIDERATIONS

The PA75CD and CX have a large exposed copper heat tab to which the monolithic is directly attached. The PA75CD and CX may require a thermal washer, which is electrically insulating since the tab is directly tied to -V_s. This can result in a thermal impedance RCS of up to 1°C/W or greater.

The PA75CC has a large exposed integrated copper heatslug to which the monolithic is directly attached. The solder connection of the heatslug to a minimum of 1 square inch foil area of the printed circuit board will result in thermal performance of 25°C/W junction to air rating of the PA75CC. Solder connection to an area of 1 to 2 square inches of foil is required for minimal power applications.

Where the PA75CC is used in higher power applications, it is necessary to use surface mount techniques of heatsinking. Surface mount techniques include the use of a surface mount fan in combination with a surface mount heatsink on the backside of the FR4/ PC board with through hole thermal vias. Other highly thermal conductive substrate board materials are available for maximum heat sinking.

POWER DERATING



MOUNTING PRECAUTIONS

1. Always use a heat sink. Even unloaded the PA75 can dissipate up to .4 watts.
2. Avoid bending the leads. Such action can lead to internal damage.
3. Always fasten the tab of the CD and CX package to the heat sink before the leads are soldered to fixed terminals.
4. Strain relief must be provided if there is any probability of axial stress to the leads.